UNR7231 (UN7231)

Silicon NPN epitaxial planar type

For low-frequency amplification

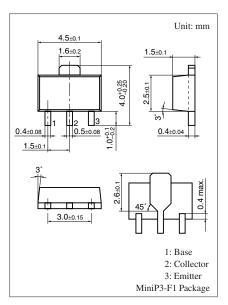
■ Features

- \bullet High forward current transfer ratio h_{FE}
- Costs can be reduced through downsizing of the equipment and reduction of the number of parts.

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	20	V	
Collector-emitter voltage (Base open)	V _{CEO}	20	V	
Collector current	I_C	0.7	A	
Peak collector current	I_{CP}	1.5	A	
Total power dissipation *	P_{T}	1.0	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note) *: Printed circuit board: Copper foil area of 1 cm² or more, and the board thickness of 1.7 mm for the collector portion



Marking Symbol: IC

Internal Connection

$$\begin{array}{c}
R_{1}(1 \text{ k}\Omega) \\
B \circ - W \downarrow \\
R_{2} \\
(47 \text{ k}\Omega)
\end{array}$$

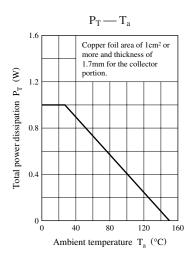
\blacksquare Electrical Characteristics $~T_a = 25^{\circ}C \pm 3^{\circ}C$

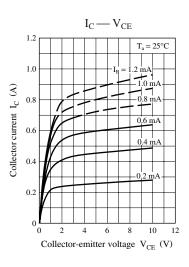
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V_{CBO}	$I_C = 10 \ \mu A, I_E = 0$	20			V
Collector-emitter voltage (Base open)	V_{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	20			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 15 \text{ V}, I_E = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 15 \text{ V}, I_B = 0$			10	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 14 \text{ V}, I_C = 0$			0.5	mA
Forward current transfer ratio *	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 150 \text{ mA}$	800		2100	_
Collector-emitter saturation voltage *	V _{CE(sat)}	$I_C = 500 \text{ mA}, I_B = 5 \text{ mA}$			0.4	V
Input resistance	R_1		0.7	1.0	1.3	kΩ
Resistance ratio	R ₁ /R ₂		0.016	0.021	0.025	
Transition frequency	f_T	$V_{CB} = 20 \text{ V}, I_E = -20 \text{ mA}, f = 200 \text{ MHz}$		55		MHz

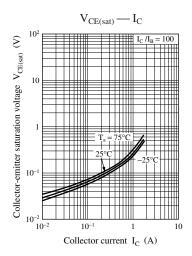
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

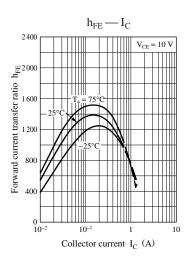
2. *: Pulse measurement

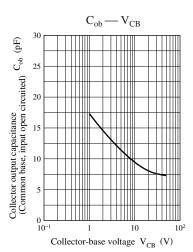
Note) The part number in the parenthesis shows conventional part number.











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